NSN 5961-01-026-6120

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-026-6120 **Inclosure Material:** Glass and metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.667 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.2 regulator voltage **Current Rating Per Characteristic:** 20.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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